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FDMS86163P

P-Channel PowerTrench[®] MOSFET

-100 V, -50 A, 22 mΩ

Features

- Max $r_{DS(on)}$ = 22 mΩ at $V_{GS} = -10$ V, $I_D = -7.9$ A
- Max $r_{DS(on)}$ = 30 mΩ at $V_{GS} = -6$ V, $I_D = -5.9$ A
- Very low RDS-on mid voltage P-channel silicon technology optimised for low Qg
- This product is optimised for fast switching applications as well as load switch applications
- 100% UIL tested
- RoHS Compliant

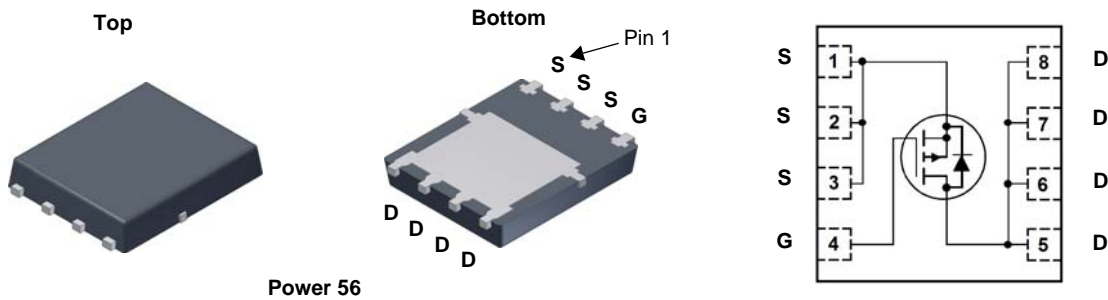


General Description

This P-Channel MOSFET is produced using Fairchild Semiconductor's advanced PowerTrench[®] process that has been especially tailored to minimize the on-state resistance and yet maintain superior switching performance.

Applications

- Active Clamp Switch
- Load Switch



MOSFET Maximum Ratings $T_A = 25$ °C unless otherwise noted

Symbol	Parameter	Rated	Units
V_{DS}	Drain to Source Voltage	-100	V
V_{GS}	Gate to Source Voltage	±25	V
I_D	Drain Current -Continuous	$T_C = 25$ °C	A
	-Continuous	$T_A = 25$ °C (Note 1a)	
	-Pulsed	(Note 4)	
E_{AS}	Single Pulse Avalanche Energy	(Note 3)	mJ
P_D	Power Dissipation	$T_C = 25$ °C	W
	Power Dissipation	$T_A = 25$ °C (Note 1a)	
T_J, T_{STG}	Operating and Storage Junction Temperature Range	-55 to +150	°C

Thermal Characteristics

$R_{\theta JC}$	Thermal Resistance, Junction to Case	1.2	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient (Note 1a)	50	

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDMS86163P	FDMS86163P	Power 56	13 "	12 mm	3000 units

Electrical Characteristics $T_J = 25\text{ }^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
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Off Characteristics

BV_{DSS}	Drain to Source Breakdown Voltage	$I_D = -250\text{ }\mu\text{A}, V_{GS} = 0\text{ V}$	-100			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = -250\text{ }\mu\text{A}$, referenced to $25\text{ }^\circ\text{C}$		-59		mV/ $^\circ\text{C}$
I_{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = -80\text{ V}, V_{GS} = 0\text{ V}$			-1	μA
I_{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 25\text{ V}, V_{DS} = 0\text{ V}$			± 100	nA

On Characteristics

$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = -250\text{ }\mu\text{A}$	-2	-2.8	-4	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = -250\text{ }\mu\text{A}$, referenced to $25\text{ }^\circ\text{C}$		6.2		mV/ $^\circ\text{C}$
$r_{DS(on)}$	Static Drain to Source On Resistance	$V_{GS} = -10\text{ V}, I_D = -7.9\text{ A}$		17.8	22	m Ω
		$V_{GS} = -6\text{ V}, I_D = -5.9\text{ A}$		21.3	30	
		$V_{GS} = -10\text{ V}, I_D = -7.9\text{ A}, T_J = 125\text{ }^\circ\text{C}$		29	36	
g_{FS}	Forward Transconductance	$V_{DS} = -10\text{ V}, I_D = -7.9\text{ A}$		29		S

Dynamic Characteristics

C_{iss}	Input Capacitance	$V_{DS} = -50\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$		3070	4085	pF
C_{oss}	Output Capacitance			501	670	pF
C_{riss}	Reverse Transfer Capacitance			21	35	pF
R_g	Gate Resistance		0.1	2.6	5.3	Ω

Switching Characteristics

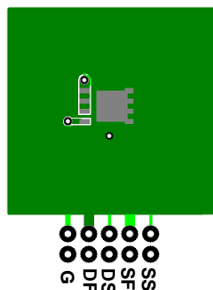
$t_{d(on)}$	Turn-On Delay Time	$V_{DD} = -50\text{ V}, I_D = -7.9\text{ A}, V_{GS} = -10\text{ V}, R_{GEN} = 6\text{ }\Omega$		17	30	ns	
t_r	Rise Time			8.8	18	ns	
$t_{d(off)}$	Turn-Off Delay Time			33	53	ns	
t_f	Fall Time			6.9	14	ns	
Q_g	Total Gate Charge		$V_{GS} = 0\text{ V to } -10\text{ V}$		42	59	nC
Q_g	Total Gate Charge	$V_{GS} = 0\text{ V to } -6\text{ V}$	$V_{DD} = -50\text{ V}, I_D = -7.9\text{ A}$		26	37	nC
Q_{gs}	Gate to Source Charge				11.8		nC
Q_{gd}	Gate to Drain "Miller" Charge				7.1		nC

Drain-Source Diode Characteristics

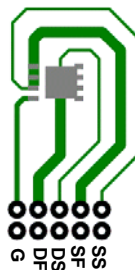
V_{SD}	Source to Drain Diode Forward Voltage	$V_{GS} = 0\text{ V}, I_S = -7.9\text{ A}$ (Note 2)		-0.81	-1.3	V
		$V_{GS} = 0\text{ V}, I_S = -2\text{ A}$ (Note 2)		-0.75	-1.2	
t_{rr}	Reverse Recovery Time	$I_F = -7.9\text{ A}, di/dt = 100\text{ A}/\mu\text{s}$		63	102	ns
Q_{rr}	Reverse Recovery Charge			132	210	nC

Notes:

- $R_{\theta JA}$ is determined with the device mounted on a 1 in² pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. $R_{\theta JC}$ is guaranteed by design while $R_{\theta CA}$ is determined by the user's board design.



a) $50\text{ }^\circ\text{C/W}$ when mounted on a 1 in² pad of 2 oz copper



b) $125\text{ }^\circ\text{C/W}$ when mounted on a minimum pad of 2 oz copper.

2. Pulse Test: Pulse Width < 300 μs , Duty cycle < 2.0%.

3. Starting $T_J = 25\text{ }^\circ\text{C}$; P-ch: L = 3 mH, $I_{AS} = -18\text{ A}$, $V_{DD} = -100\text{ V}$, $V_{GS} = -10\text{ V}$. 100% test at L = 0.1 mH, $I_{AS} = -58\text{ A}$.

4. Pulse Id refers to Figure.11 Forward Bias Safe Operation Area.

Typical Characteristics $T_J = 25\text{ }^\circ\text{C}$ unless otherwise noted

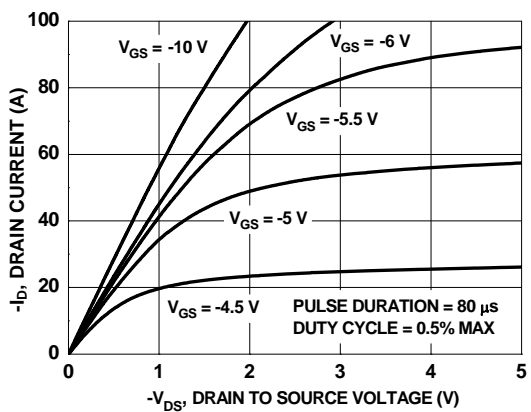


Figure 1. On Region Characteristics

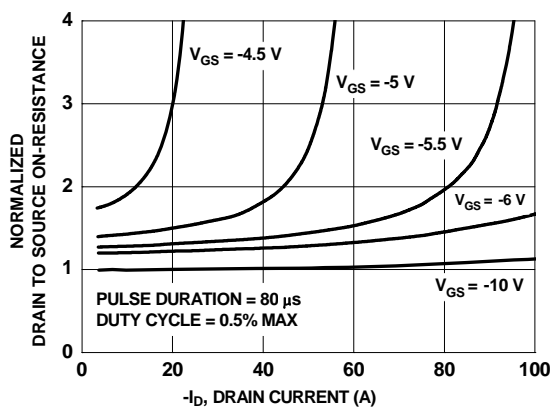


Figure 2. Normalized On-Resistance vs Drain Current and Gate Voltage

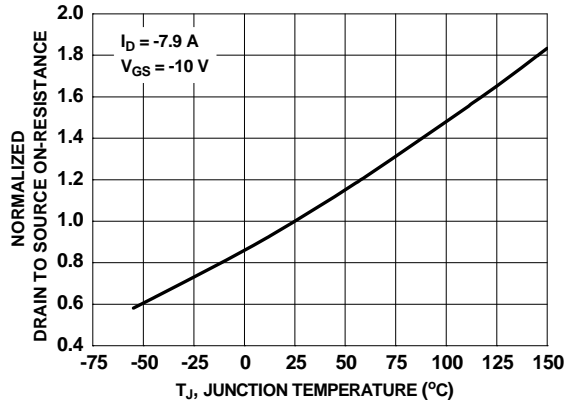


Figure 3. Normalized On Resistance vs Junction Temperature

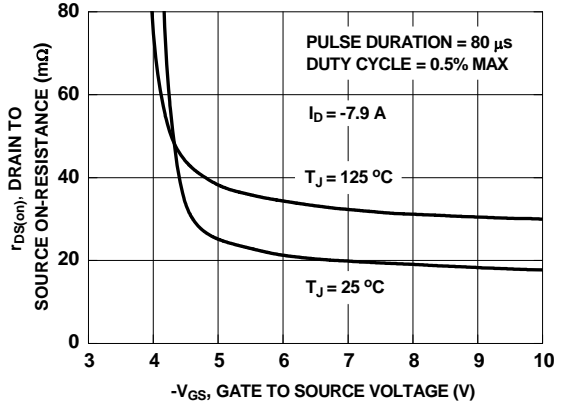


Figure 4. On-Resistance vs Gate to Source Voltage

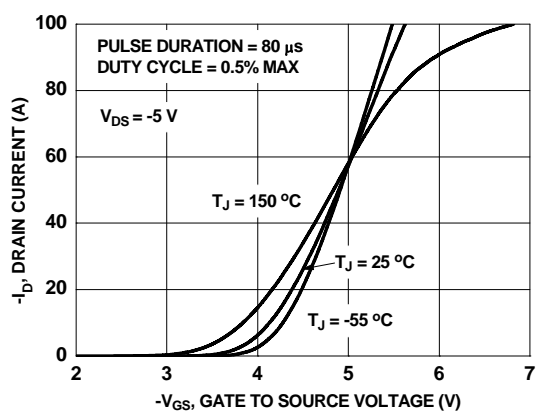


Figure 5. Transfer Characteristics

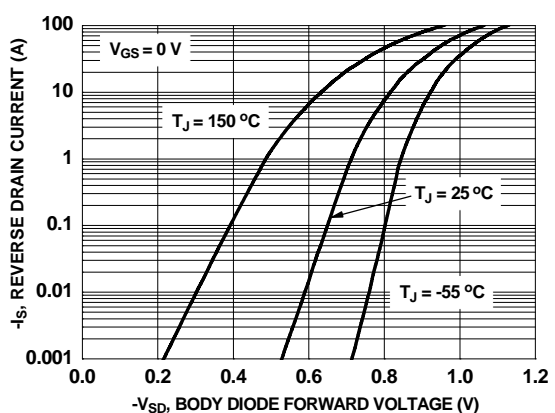


Figure 6. Source to Drain Diode Forward Voltage vs Source Current

Typical Characteristics $T_J = 25\text{ }^\circ\text{C}$ unless otherwise noted

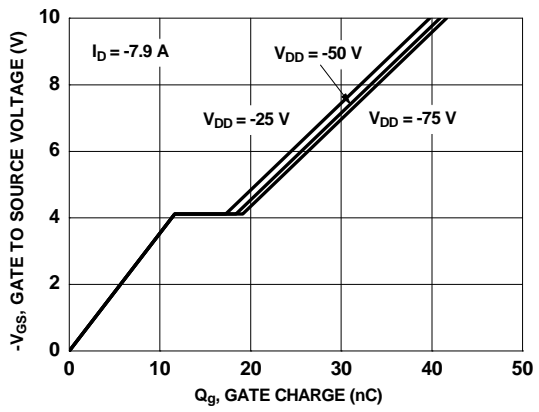


Figure 7. Gate Charge Characteristics

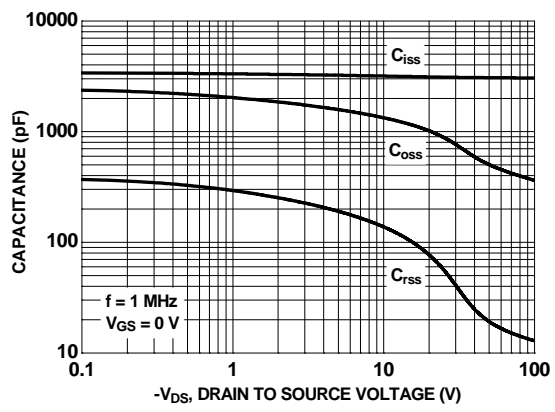


Figure 8. Capacitance vs Drain to Source Voltage

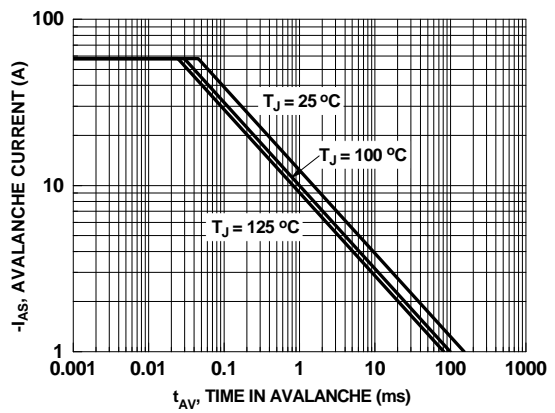


Figure 9. Unclamped Inductive Switching Capability

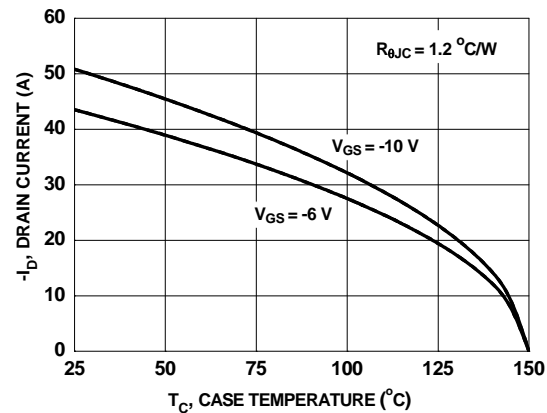


Figure 10. Maximum Continuous Drain Current vs Case Temperature

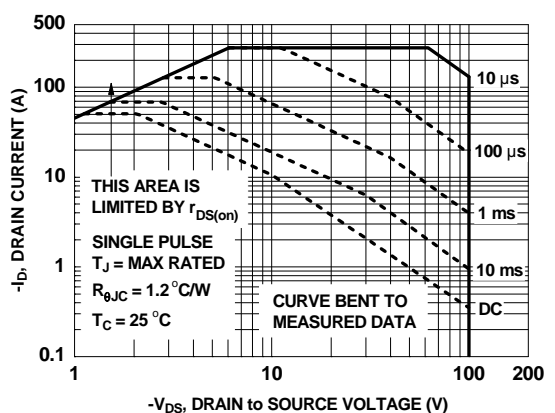


Figure 11. Forward Bias Safe Operating Area

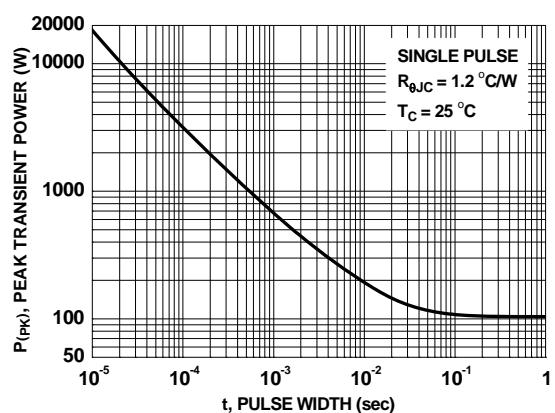


Figure 12. Single Pulse Maximum Power Dissipation

Typical Characteristics $T_J = 25\text{ }^\circ\text{C}$ unless otherwise noted

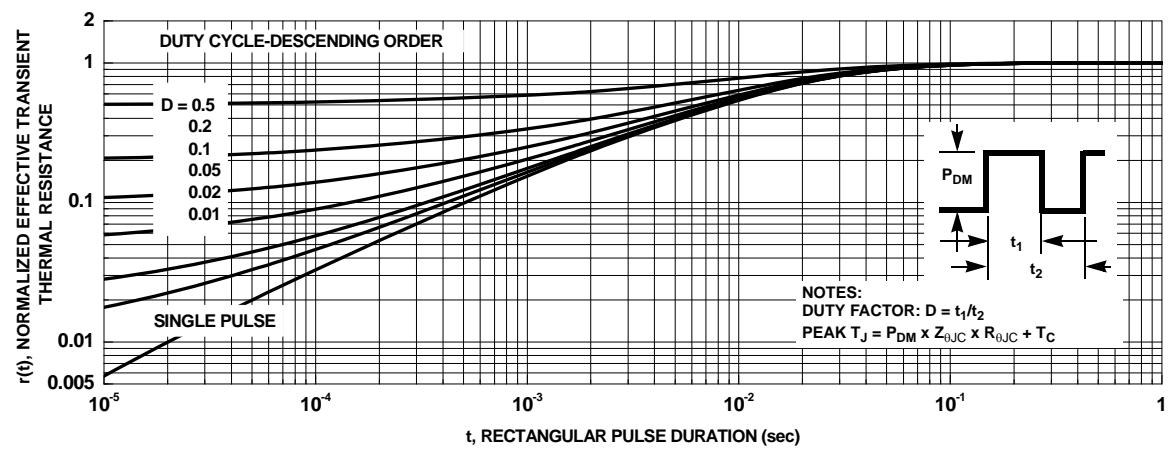
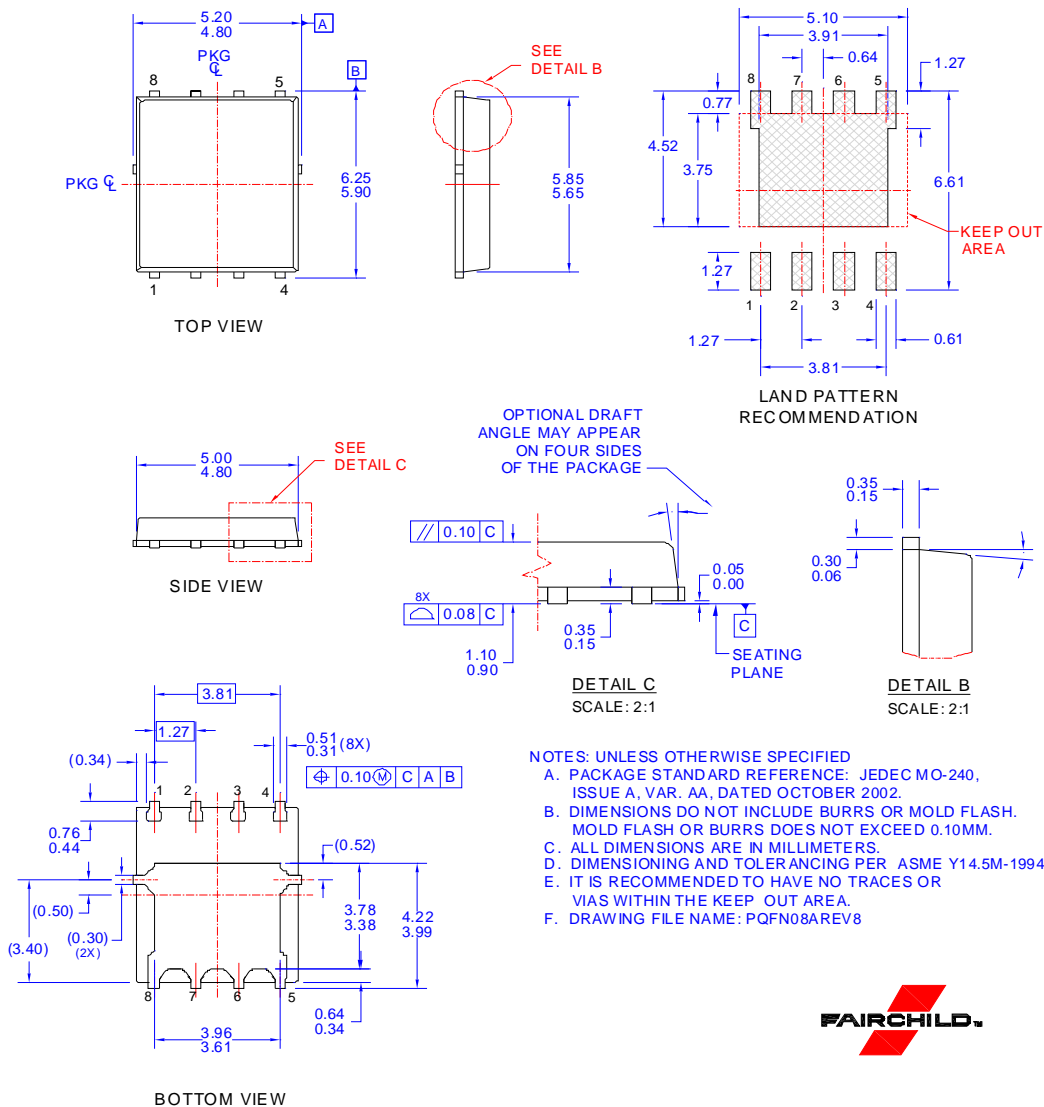


Figure 13. Junction-to-Case Transient Thermal Response Curve

Dimensional Outline and Pad Layout




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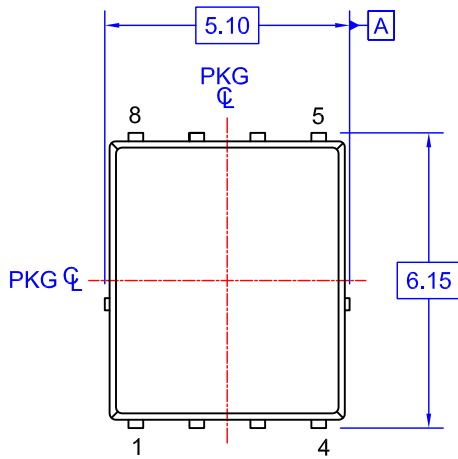
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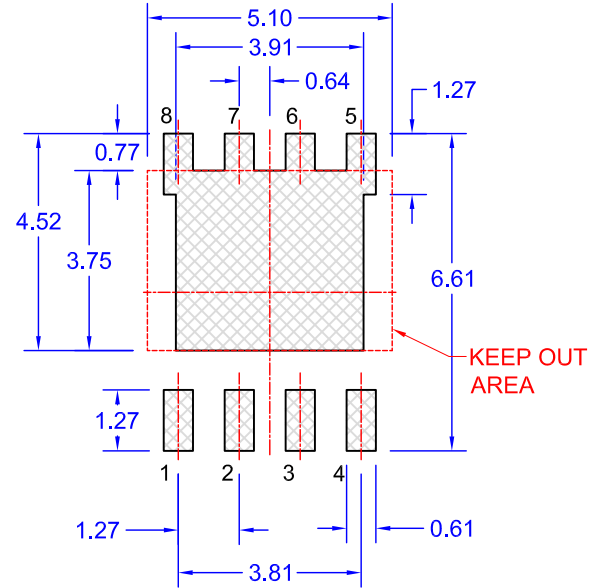
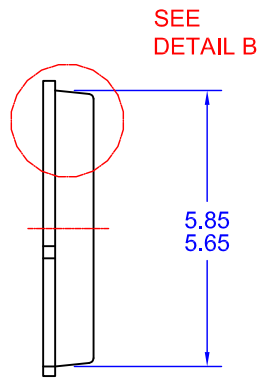
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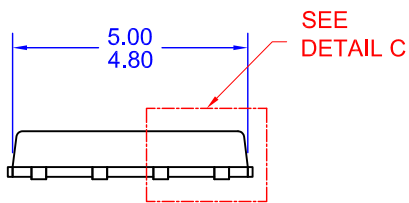
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TOP VIEW

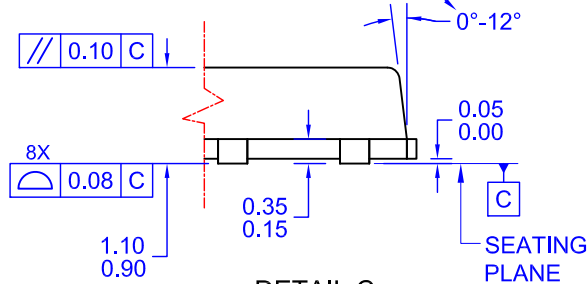


LAND PATTERN RECOMMENDATION

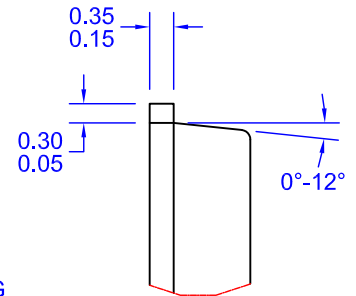


SIDE VIEW

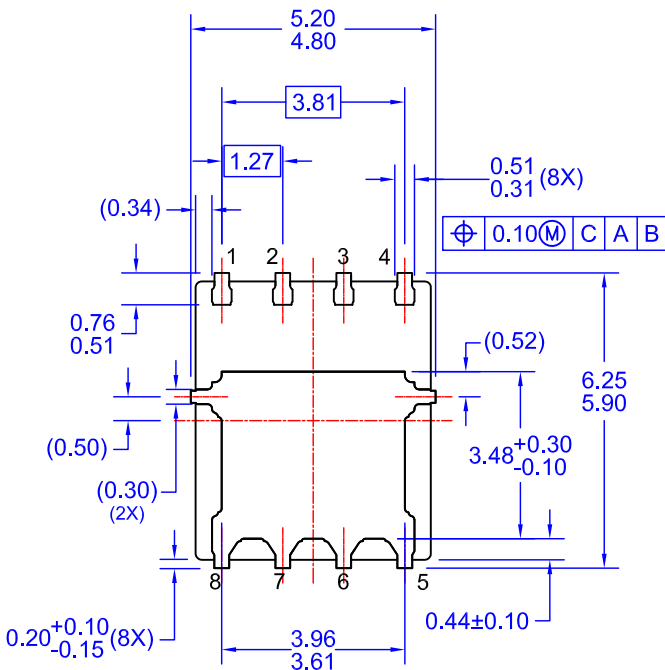
OPTIONAL DRAFT ANGLE MAY APPEAR ON FOUR SIDES OF THE PACKAGE



DETAIL C
SCALE: 2:1



DETAIL B
SCALE: 2:1



BOTTOM VIEW

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- D. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-2009.
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